

## **KSD1021**

## **Audio Frequency Power Amplifier**

- Complement to KSB811
- Collector Dissipation : P<sub>C</sub>=350mW



1.Emitter 2. Collector 3. Base

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current	1	А
P <sub>C</sub>	Collector Power Dissipation	350	mW
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0	30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_{E}$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	70		400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			1.2	V
f <sub>T</sub>	Current Gain Band Width Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		130	- 111	MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB}=6V$ , $I_{E}=0$ , $f=1MHz$		16	L OL	pF

### **h**<sub>FE</sub> Classification

Classification	0	Y	G
h <sub>FE</sub>	70 ~ 140	120 ~ 240	200 ~ 400

# **Typical Characteristics**

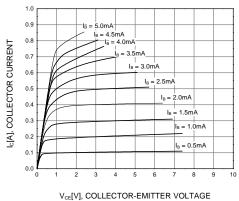
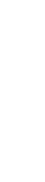
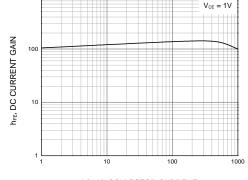


Figure 1. Static Characteristic





 $I_{\text{c}}[\text{mA}]$ , COLLECTOR CURRENT

Figure 2. DC current Gain

1000

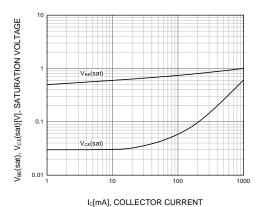
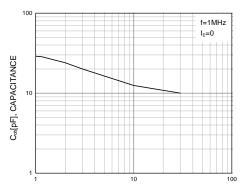


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage



 $V_{\text{CB}}[V],\,COLLECTOR\text{-BASE}\,\,VOLTAGE$ 

Figure 4. Collector Output Capacitance

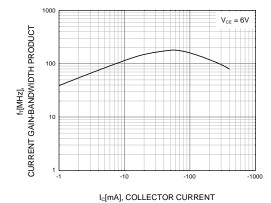


Figure 5. Current Gain Bandwidth Product

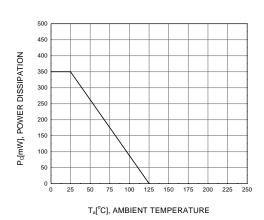
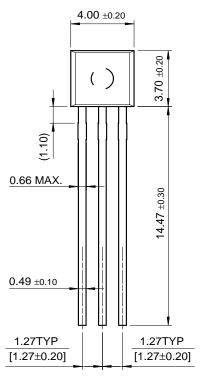


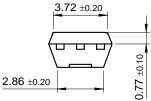
Figure 6. Power Derating

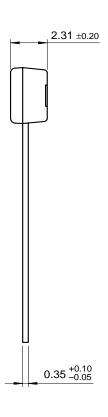
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# **Package Demensions**

# TO-92S







Dimensions in Millimeters

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